

Full Name:
SID :

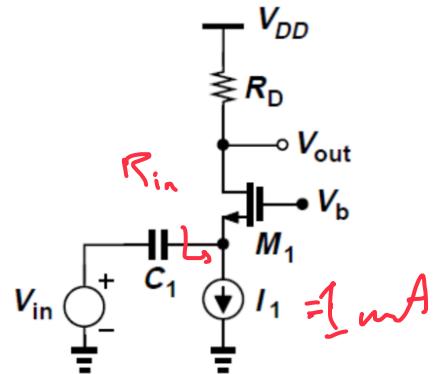
Grade: /100

Assume: $V_{DD}=1.2V$, $|V_{th,n,p}|=0.3V$, $\mu_n C_{ox} = \frac{0.5mA}{V^2}$, $\mu_n = 2\mu_p$, $\lambda_p = \lambda_n = 0.1V^{-1}$, $\gamma = 0$ for both NMOS and PMOS devices.

$$\Rightarrow \mu_p C_{ox} = \frac{0.25mA}{V^2}$$

- 35
1. (30 pts) Assuming $I_1 = 1mA$ (ideal current source), and C_1 is an AC-coupling capacitor (will be shorted in small-signal models and open for DC/bias analysis):

- Find $(W/L)_1$ such that the input impedance will be 50Ω .
- Write down the small-signal gain equation in terms of small-signal parameters and R_D .
- Find R_D such that V_{out} bias point will be $V_{DD}/2$.
- Find V_b to achieve a gain of 50 (you can assume $\lambda = 0$ for this part). For that R_D .
- If we realize I_1 current-source with a single NMOS device at a fixed gate bias of $V_{DD}/2$, what would be the W/L for that device?
- What can be minimum V_b to make sure all transistors are in saturation?
- Assuming $V_{in} = 0.5 + 0.01\sin(\omega t) V$, what is the overall (bias and small-signal) V_{out} ?



$$a) R_{in} \approx \frac{1}{g_m} \Rightarrow g_m = \frac{1}{50} = 20mS = \frac{2 \cdot 1mA}{V_{od}} = \frac{2mA}{V_{od}}$$

$$\Rightarrow V_{od} = \frac{2mA}{20mS} = 0.1V$$

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} V_{od}^2 \Rightarrow 1mA = \frac{1}{2} \times \frac{0.5mA}{V^2} \times \frac{W}{L} \times (0.1)^2$$

$$\Rightarrow \boxed{(W/L) = 400}$$

$$b) A_{ve} = \frac{V_{out}}{V_{in}} = g_m R_D$$

$$C) V_{out,DC} = V_{DD} - I_D \cdot R_D = V_{DD}/2$$

$$\Rightarrow R_D \cdot I_D = \frac{V_{DD}}{2} \Rightarrow R_D = \frac{V_{DD}}{2I_D} = \frac{1.2V}{2 \times 1mA} = 600\Omega$$

$$d) A_v = g_m R_D = 20mS \times 0.6k\Omega = 12$$

$$e) I_D = \frac{1}{2} M_n C_{ox} \frac{W}{L} (V_{GS} - V_{th})^2$$

$$1mA = \frac{1}{2} \times \frac{0.5mA}{V^2} \times \frac{W}{L} (0.6 - 0.3)^2$$

$$\Rightarrow \frac{W}{L} = \frac{400}{9} \approx 44$$

$$f) V_b \text{ min} = V_{GS} + V_{OD, \text{Current Source}}$$

$$\text{from port a} \leftarrow \underbrace{0.1}_{0.1} + \underbrace{0.3}_{0.3} + \underbrace{V_{OD,CS}^{0.3}}_{\text{from port e}} = 0.7V$$

$$g) V_{out} = \underbrace{V_{out,DC}}_{V_{DD}/2 = 0.6V} + \underbrace{V_{out}}_{A_v \times (0.01 \sin(\omega t))}$$

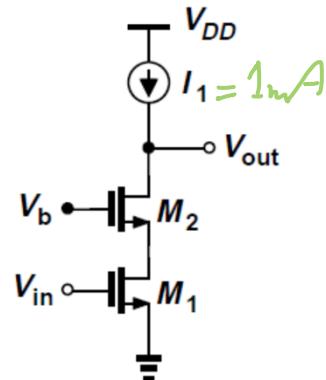
$$\Rightarrow V_{out} = 0.6 + 0.12 \sin(\omega t)$$

30

2. (40 pts) Design a Cascode amplifier as shown in figure below to achieve a gain of 10^4 . Assume an ideal current source of $I_1 = 1mA$ and $g_m r_o \gg 1$.

16 4

- If $V_{GS1} = V_{GS2}$, what should be the value of V_{GS1} ?
- Find R_{out} and R_{in} values for this amplifier.
- Calculate optimal V_b to maximize the output swing.
- To realize the current source load, we will use a PMOS active load with $W/L = 80$. Assume the bias current will remain at 1mA, what would be the $V_{OD} (=V_{GS}-V_{th})$ for this device?
- What's the output swing range?
- ~~If L_D will be doubled, how does the gain will change? Find the new gain value.~~



$$\frac{2I}{V_{od}} \times \frac{1}{\lambda I}$$

a) $A_v \approx \underbrace{\frac{g_{m1} r_o}{2}}_{V_{od1} \lambda} \times \underbrace{\frac{g_{m2} r_o}{2}}_{V_{od2} \lambda} = \left(\frac{2}{V_{od} \cdot \lambda} \right)^2 = \left(\frac{20}{V_{od}} \right)^2$

For $A_v = 10^4 \Rightarrow \frac{20}{V_{od}} = 100 \Rightarrow \boxed{V_{od} = 0.2V}$

b) $R_{in} = \infty$

$$\frac{1}{0.1 \times 1mA} = 10k\Omega$$

$R_{out} \approx r_o \times \underbrace{(g_{m2} r_o)}_{100} = \frac{1}{2I_D} \times 100 = \boxed{1M\Omega}$

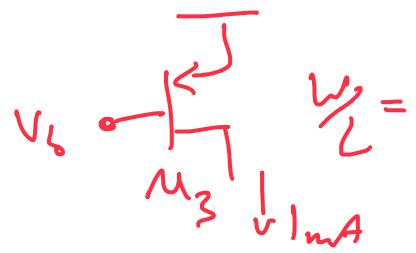
c) $V_b_{min} = V_{od1} + V_{GS2} = 2V_{od} + V_{Th} = 2 \times 0.2 + 0.3$

$= 0.7V$

d)

$$I_{mA} = \frac{1}{2} \times \frac{0.25mA}{\omega^2} \times \cancel{\frac{V_L}{2}} \times |V_{od}|^2$$

80°



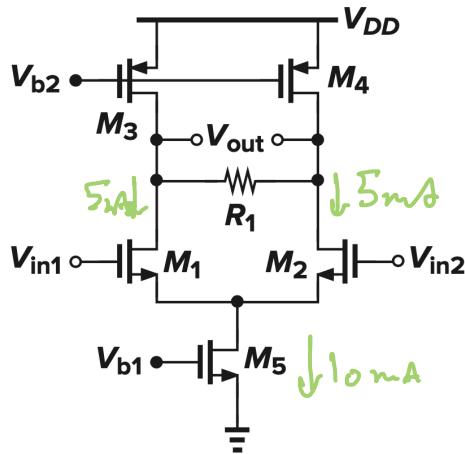
$$\Rightarrow \boxed{|V_{od}| = 0.1V}$$

$$e) V_{out, max} = V_{DD} - V_{od_3} = 1.2 - 0.1 = 1.1V$$

$$V_{out, min} = V_{DD_1} + V_{op_2} = 0.2 + 0.2 = 0.4V$$

$$V_{out, swing pp} = V_{out, max} - V_{out, min} = 1.1 - 0.4 = \boxed{0.7V}$$

3. (35 pts) For the differential amplifier shown below:



- Assuming the target over-drive voltage (V_{od}) for all the transistors is 0.2V, find the V_{b1} , V_{b2} , and V_{out} values.
- Find $(W/L)_{1,2}$, $(W/L)_{3,4}$, & $(W/L)_5$ such that current tail will be 10mA.
- Draw the differential-mode half circuit and calculate the differential gain ($\frac{v_{o2}-v_{o1}}{v_{id}}$) in terms of small-signal parameters (g_{ms} , r_{os} , and R_1)?
- Draw the common-mode half circuit and calculate single ended common-mode gain ($\frac{v_{o1/2}}{v_{cm}}$) in terms of small-signal parameters (g_{ms} , r_{os} , and R_1)?
- For a differential gain of -10, what should be the value of R_1 ?
- Find differential output peak-to-peak swing.
- Find the acceptable input common-mode ($V_{CM,in}$) min. for this amplifier.

$$a) V_{b2} = V_{DD} - |V_{GS_{2,4}}| = 1.2 - (0.2 + 0.3) = 0.7 \text{ V}$$

$$V_{b1} = V_{GS_5} = V_{GP_5} + v_{Th} = 0.2 + 0.3 = 0.5 \text{ V}$$

$$b) 10 \text{ mA} = \frac{1}{2} \times \frac{0.5 \text{ mA}}{L^2} \times \left(\frac{W}{L}\right)_5 \times (0.2)^2$$

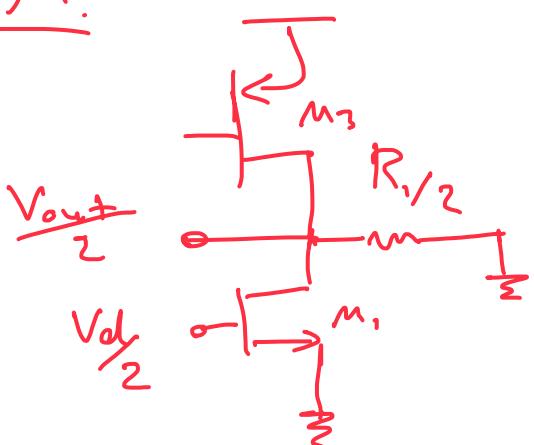
$$\Rightarrow \left(\frac{W}{L}\right)_5 = 1000$$

$$M_{1,2} \text{ have half current \& same } V_{od} \Rightarrow \left(\frac{W}{L}\right)_{1,2} = \frac{500}{5}$$

$M_3, 4$ have half current, same V_{od} , but $\mu_p = \frac{\mu_n}{2}$

$$\Rightarrow \boxed{(W/L)_{3,4} = 1000}$$

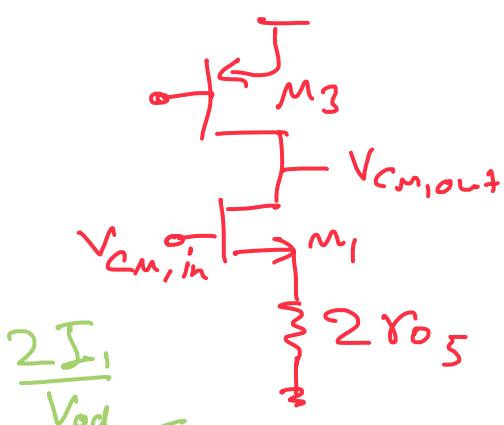
c) D.M.



$$A_{ve} = -g_{m1} \times \left(\frac{R_1}{2} || V_o, || V_{o3} \right)$$

$$\approx -g_{m1} \frac{R_1}{2}$$

d)



$$A_{ve2} \frac{V_{out,cm}}{V_{in,cm}} = \frac{-g_{m1} V_{o3}}{1 + g_{m1} \times 2V_{o5}}$$

e) $A_{ve} \approx -g_{m1}' \frac{R_1}{2} \Rightarrow \frac{2 \times 5mA}{0.2} \times \frac{R_1}{2} = 10$

$$\Rightarrow R_1 = \frac{2}{5mA} = 400\Omega$$

f) Single-ended $\rightarrow V_{max} = V_{pp} - V_{od2} = 1.2 - 0.2 = 1V$
 $V_{min} = V_{od1} + V_{od2} = 0.2 + 0.2 = 0.4V$

$$\Rightarrow \text{Diff. Swing range} = 2 \times (1 - 0.4) = \underline{\underline{1.2V}}$$

g) $V_{in,cm} > V_{gs1} + V_{od5} = 0.2 + 0.3 + 0.2 = \underline{\underline{0.7V}}$